

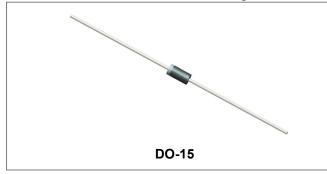




# HER208G

### HIGH EFFICIENCY RECTIFIERS

Reverse Voltage - 1000 Volts Forward Current - 2.0 Amperes



#### **Features**

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-O
- · Ultra-fast switching for high efficiency
- Low reverse leakage
- Glass Passivated Die Construction
- · High forward surge current capability
- High temperature soldering guaranteed 250℃/10 seconds,
  0.375" (9.5mm) lead length,5lbs. (2.3kg) tension
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



#### **Mechanical Data**

- Case: JEDEC DO-15 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.014 ounce, 0.40 grams

### **Maximum Ratings**

Characteristics	Symbol	Condition	Max.	Units
Repetitive Peak Reverse Voltage	$V_{RRM}$	-	1000	V
RMS Voltage	V <sub>RMS</sub>	-	700	V
DC Blocking Voltage	V <sub>DC</sub>	-	1000	V
Average Forward Current	I <sub>F (AV)</sub>	50% duty cycle @TA = 50°C rectangular wave form	2.0	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	60	Α

#### **Electrical Characteristics**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 2.0A, Pulse, T <sub>J</sub> = 25°C	1.41	1.7	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}$	3	5	μА
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 100^{\circ}C$	-	100	μА
Junction Capacitance	Сл	$@V_R = 4V, T_C = 25 °C$ $f_{SIG} = 1MHz$	20	-	pF
Reverse Recovery Time	Trr	IF=0.5A,IR=1.0A,Irr=0.25A	-	75	ns

<sup>\*</sup> Pulse width < 300 μs, duty cycle < 2%

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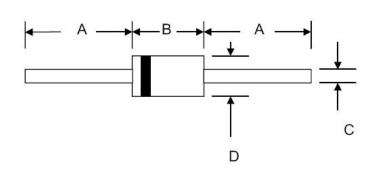




## **Thermal-Mechanical Specifications**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	-	50	°C/W

### **Mechanical Dimensions DO-15**



SYMBOL	Millimeters		Inches		
OTMBOL	Min.	Max.	Min.	Max.	
А	25.4	-	1.000	-	
В	5.5	7.62	0.217	0.300	
С	0.7	0.9	0.028	0.034	
D	2.6	3.6	0.104	0.140	

### **Ordering Information**

Device	Package	Shipping	
HER208G	DO-15 (Pb-Free)	3000pcs /tape	

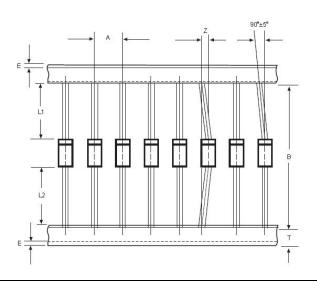
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



HER208G = Part Name

### **Carrier Tape Specification DO-15**



SYMBOL	Millimeters		
	Min.	Max.	
А	4.50	5.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
Е	-	0.80	
IL1-L2I	-	1.0	

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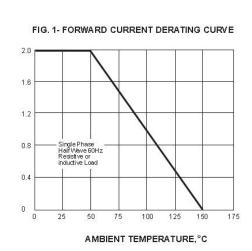


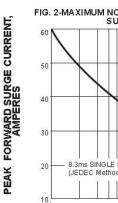


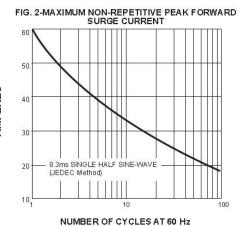


### **Ratings and Characteristics Curves**











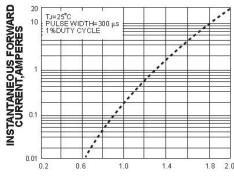
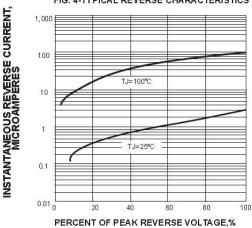
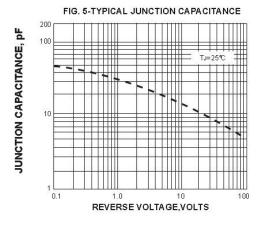


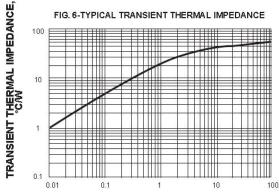
FIG. 4-TYPICAL REVERSE CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE, VOLTS







t, PULSE DURATION, sec.

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